DA5J110V

Silicon epitaxial planar type

For high speed switching circuits

■ Features

- Short reverse recovery time t_{rr}
- Contributes to miniaturization of sets, reduction of component count.
- Eco-friendly Halogen-free package

■ Packaging

Embossed type (Thermo-compression sealing): 3000 pcs / reel (standard)

■ Absolute Maximum Ratings $T_a = 25$ °C

| Parameter | Symbol Rating | | Unit | |
|--|------------------|--------------------|------|--|
| Reverse voltage | V _R | 80 | V | |
| Maximum peak reverse voltage | V_{RM} | 80 | V | |
| Forward current | I_{F} | 100 | mA | |
| Peak forward current *1 | I_{FM} | 225 | mA | |
| Non-repetitive peak forward surge current *2 | I_{FSM} | 500 | mA | |
| Junction temperature | T_j | T _j 150 | | |
| Storage temperature | T _{stg} | -55 to +150 | °C | |

Note) *1: Value for single diode

*2: 1 t = 1 s

■ Package

• Code

SMini5-F3-B

• Pin Name

1: Cathode-1 4: Anode-3

2: Cathode-1, 2, 3, 4 5: Anode-4

3: Anode-2

■ Marking Symbol: 28

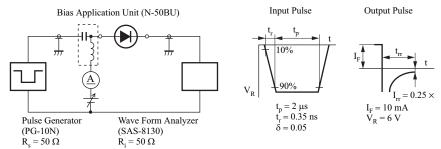
■ Internal Connection



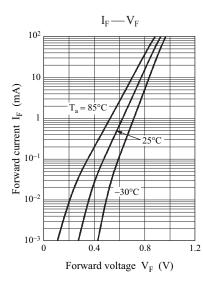
■ Electrical Characteristics $T_a = 25$ °C±3°C

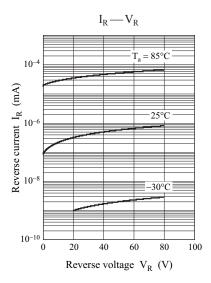
| Parameter | Symbol | Conditions | Min | Тур | Max | Unit |
|--------------------------|-----------------|---|-----|-----|-----|------|
| Forward voltage | V _F | $I_F = 100 \text{ mA}$ | | | 1.2 | V |
| Reverse voltage | V _R | $I_R = 100 \mu A$ | 80 | | | V |
| Reverse current | I_R | $V_R = 80 \text{ V}$ | | | 100 | nA |
| Terminal capacitance | C _t | $V_R = 6 \text{ V}, f = 1 \text{ MHz}$ | | | 3.5 | pF |
| Reverse recovery time *1 | t _{rr} | $I_F = 5 \text{ mA}, V_R = 6 \text{ V}, I_{rr} = 0.25 \times I_R$ | | | 5.0 | ns |
| Transistor current *2 | I_{C} | $V = \pm 8 \text{ V}, I = 1 \text{ mA}$ | | 30 | | μА |

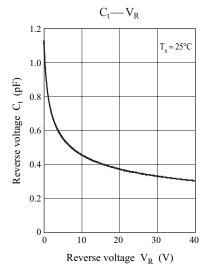
- Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring methods for diodes.
 - 2. Absolute frequency of input and output is 100 MHz
 - 3. *1: t_{rr} measurement circuit
 - *2: Lead 2 is applied current and Lead1-3 or Lead3-4 or Lead4-5 or Lead5-1 is applied voltage.



DA5J110V Panasonic



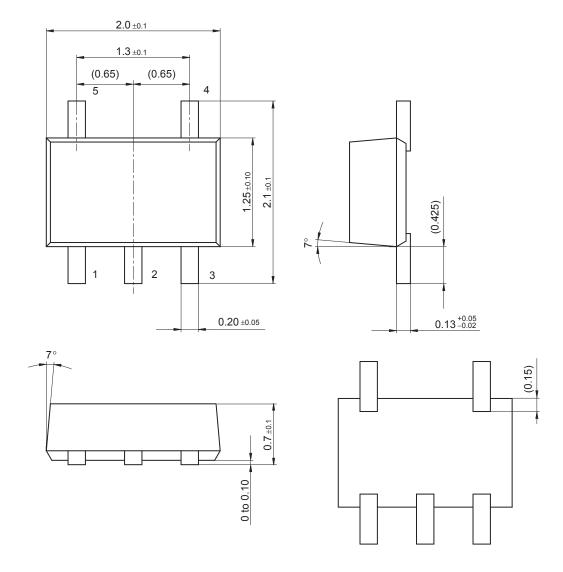




2 Ver. AED

SMini5-F3-B

Unit: mm



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